N-Channel Depletion-Mode Vertical DMOS FETs

Features

- High input impedance
- Low input capacitance
- Fast switching speeds
- Low on resistance
- Free from secondary breakdown
- Low input and output leakage

Applications

- Normally-on switches
- Solid state relays
- Converters
- Constant current sources
- Power supply circuits
- Telecom

General Description

The Supertex DN3145 is a depletion-mode (normally-on) transistor utilizing an advanced vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and with the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Ordering Information

BV_{DSX}/ BV_{DGX}	$R_{DS(ON)}$ (max)	I_{DSS} (min)	Package Options
			TO-243AA[1]
450V	60Ω	120mA	DN3145N8
			DN3145N8-G

-G indicates package is RoHS compliant ('Green')

Notes: *[1]Same as SOT-89.*

Product marking for TO-243AA:

DN1M✳

where ✳ = 2-week alpha date code

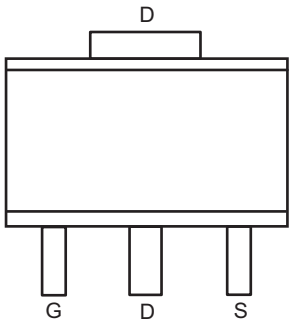
Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	BV_{DSX}
Drain-to-gate voltage	BV_{DGX}
Gate-to-source voltage	±20V
Operating and storage temperature	-55°C to +150°C
Soldering temperature*	300°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

**Distance of 1.6mm from case for 10 seconds.*

Pin Configuration



TO-243AA
(top view)

Thermal Characteristics

Package	I_D (continuous)[1]	I_D (pulsed)	Power Dissipation @T_A = 25°C	Θ_{jc} (°C/W)	Θ_{ja} (°C/W)	I_{DR}[1]	I_{DRM}
TO-243AA	100mA	300mA	1.3W[2]	34	97[2]	100mA	300mA

Notes:

1. I_D (continuous) is limited by max rated T_j.

2. Mounted on FR4 board, 25mm x 25mm x 1.57mm. Significant P_D increase possible on ceramic substrate.

Electrical Characteristics *(@25°C unless otherwise specified)*

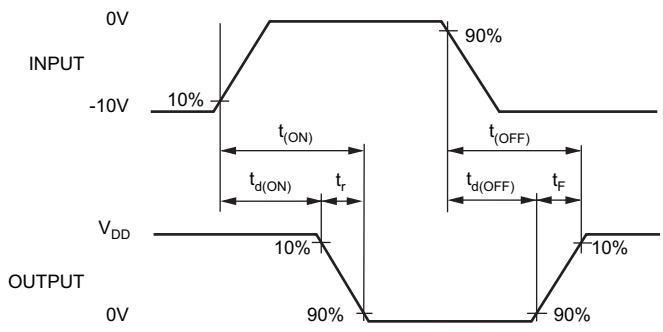
Symbol	Parameter	Min	Typ	Max	Units	Conditions
BV_{DSX}	Drain-to-source breakdown voltage	450	-	-	V	V_{GS} = -5.0V, I_D = 100µA
$V_{GS(OFF)}$	Gate-to-source OFF voltage	-1.5	-	-3.5	V	V_{DS} = 15V, I_D = 10µA
$\Delta V_{GS(OFF)}$	Change in $V_{GS(OFF)}$ with temperature	-	-	4.5	mV/°C	V_{DS} = 15V, I_D = 10µA
I_{GSS}	Gate body leakage current	-	-	100	nA	V_{GS} = ±20V, V_{DS} = 0V
$I_{D(OFF)}$	Drain-to-source leakage current	-	-	1.0	µA	V_{DS} = Max rating, V_{GS} = -5.0V
		-	-	1.0	mA	V_{DS} = 0.8 Max Rating, V_{GS} = -5.0V, T_A = 125°C
I_{DSS}	Saturated drain-to-source current	120	-	-	mA	V_{GS} = 0V, V_{DS} = 15V
$R_{DS(ON)}$	Static drain-to-source ON-state resistance	-	-	60	Ω	V_{GS} = 0V, I_D = 100mA
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with temperature	-	-	1.1	%/°C	V_{GS} = 0V, I_D = 100mA
G_{FS}	Forward transconductance	140	-	-	mmho	V_{DS} = 10V, I_D = 100mA
C_{ISS}	Input capacitance	-	-	120	pF	V_{GS} = -5.0V, V_{DS} = 25V, f = 1.0MHz
C_{OSS}	Common source output capacitance	-	-	15		
C_{RSS}	Reverse transfer capacitance	-	-	10		
$t_{d(ON)}$	Turn-ON delay time	-	-	10	ns	V_{DD} = 25V, I_D = 100mA, R_{GEN} = 25Ω,
t_r	Rise time	-	-	15		
$t_{d(OFF)}$	Turn-OFF delay time	-	-	20		
t_f	Fall time	-	-	35		
V_{SD}	Diode forward voltage drop	-	-	1.8	V	V_{GS} = -5.0V, I_{SD} = 100mA
t_{rr}	Reverse recovery time	-	800	-	ns	V_{GS} = -5.0V, I_{SD} = 100mA

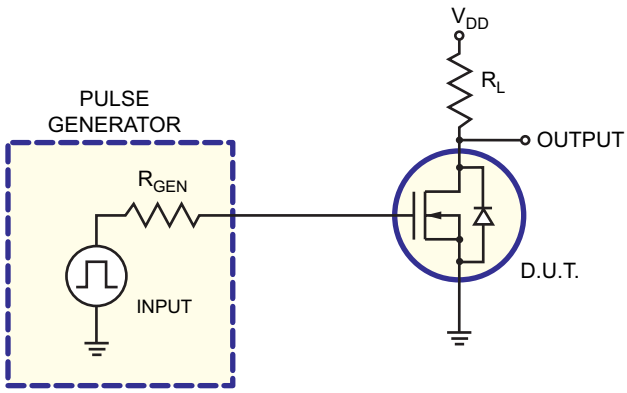
Notes:

1.All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)

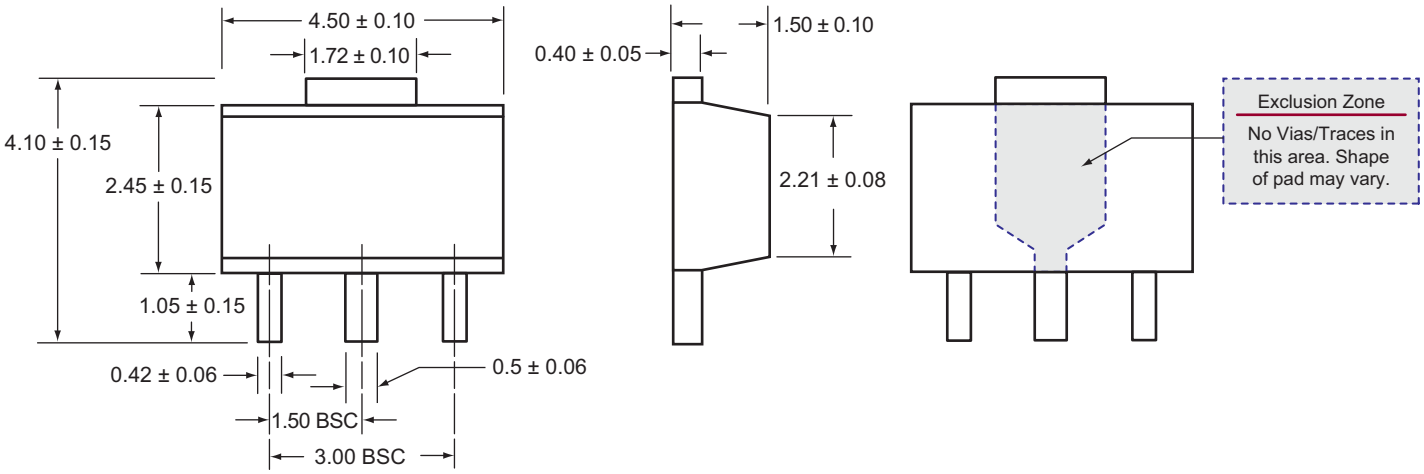
2.All A.C. parameters sample tested.

Switching Waveforms and Test Circuit





3-Lead TO-243AA (SOT-89) Surface Mount Package (N8)



Top View **Side View** **Bottom View**

Notes:
All dimensions are in millimeters; all angles in degrees.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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